



# P-Channel 1.8-V (G-S) MOSFET

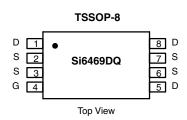
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
- 8	0.028 at V <sub>GS</sub> = - 4.5 V	± 6.0		
	0.031 at V <sub>GS</sub> = - 3.3 V	± 5.8		
	0.040 at V <sub>GS</sub> = - 2.5 V	± 5.0		
	0.065 at V <sub>GS</sub> = - 1.8 V	± 3.6		

### **FEATURES**

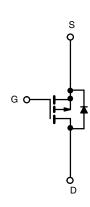
- · Halogen-free
- TrenchFET<sup>®</sup> Power MOSFETs: 1.8 V Rated







Ordering Information: Si6469DQ-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 8	V	
Gate-Source Voltage		V <sub>GS</sub>	± 8	v	
Continuous Drain Current (T, <sub>I</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	± 6.0		
Continuous Drain Current (1 <sub>J</sub> = 150 °C) <sup>3, 3</sup>	T <sub>A</sub> = 70 °C		± 5.0	Ī ,	
Pulsed Drain Current		I <sub>DM</sub>	± 30	Α	
Continuous Source Current (Diode Conduction) <sup>a, b</sup>		l <sub>S</sub> - 1.25			
Mariana Barray Disabakia alab	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.5	W	
Maximum Power Dissipation <sup>a, b</sup>	T <sub>A</sub> = 70 °C	] 'D	1.0		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular Investiga to Applicant	t ≤ 10 s	- R <sub>thJA</sub>		83	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		95		C/VV

#### Notes:

a. Surface Mounted on FR4 board.

b.  $t \le 10 \text{ s}$ .

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min		Typ.b	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45			V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA		
Zana Oata Wallana Busin Oamani	1	V <sub>DS</sub> = - 6.4 V, V <sub>GS</sub> = 0 V			- 1			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -6.4 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			- 25	μΑ		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge - 8 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 30			Α		
		$V_{GS} = -4.5 \text{ V}, I_D = -6.0 \text{ A}$	0 A 0.021					
	R <sub>DS(on)</sub>	$V_{GS} = -3.3 \text{ V}, I_D = -5.8 \text{ A}$		0.024	0.031	Ω		
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = -2.5 \text{ V}, I_D = -5.0 \text{ A}$		0.030	0.040			
		$V_{GS} = -1.8 \text{ V}, I_D = -3.6 \text{ A}$		0.048	0.065			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 8 V, I <sub>D</sub> = - 6.0 A		18		S		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 1.25 A, V <sub>GS</sub> = 0 V		- 0.68	- 1.1	V		
Dynamic <sup>b</sup>								
Total Gate Charge	$Q_g$			20	40	nC		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -6.0 \text{ A}$		4.5				
Gate-Drain Charge	$Q_{gd}$			3.6				
Turn-On Delay Time	t <sub>d(on)</sub>			20	50	ns		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 6 V, $R_L$ = 6 $\Omega$		30	60			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ - 1 A, $V_{GEN}=$ - 4.5 V, $R_G=6~\Omega$		85	150			
Fall Time	t <sub>f</sub>			50	90			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.25 A, dl/dt = 100 A/μs		50	100			

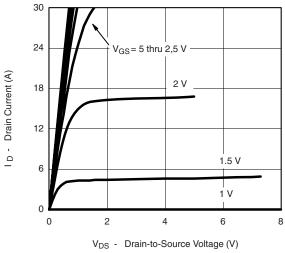
#### Notes:

- a. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

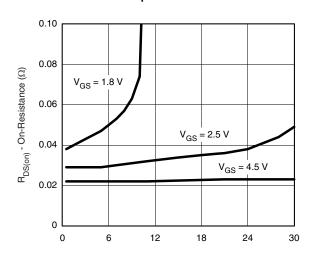
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

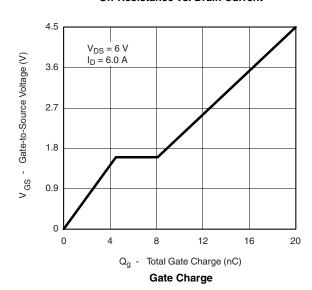


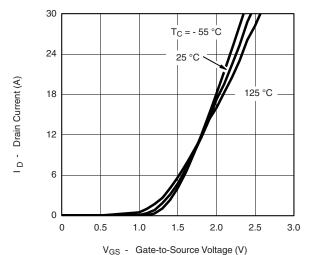
Output Characteristics



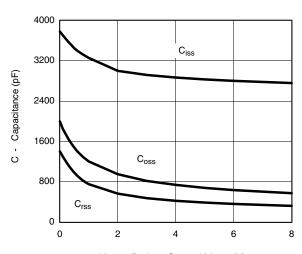
I<sub>D</sub> - Drain Current (A)

On-Resistance vs. Drain Current

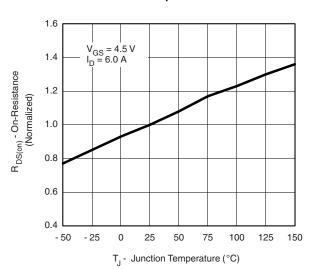




Transfer Characteristics



V<sub>DS</sub> - Drain-to-Source Voltage (V) **Capacitance** 

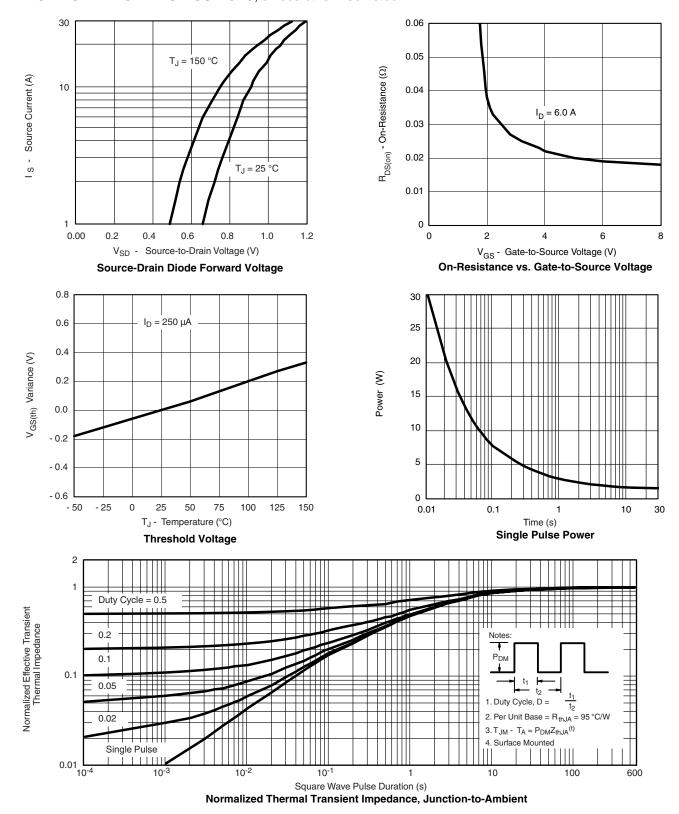


On-Resistance vs. Junction Temperature

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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?70858">http://www.vishay.com/ppg?70858</a>.



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